# Switch-mode Power Rectifiers

This LFPAK ultrafast rectifier provides fast switching performance with soft recovery in a compact thermally efficient package. The LFPAK package provides an excellent alternative to the DPAK, offering thermal performance nearly as good in a package occupying less than half the board space. Its low profile makes it a good option for flat panel display and other applications with limited vertical clearance. The device offers low leakage over temperature making it a good match for applications requiring low quiescent current.

#### **Features**

- New Package Provides Capability of Inspection and Probe After Board Mounting
- Low Forward Voltage Drop
- 175°C Operating Junction Temperature
- Excellent Ability to Absorb Stresses Associated with Power Temperature Cycling
- NRV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

## **Mechanical Characteristics:**

- Case: Epoxy, Molded
- Epoxy Meets Flammability Rating UL 94-0 @ 0.125 in.
- Lead Finish: 100% Matte Sn (Tin)
- Lead and Mounting Surface Temperature for Soldering Purposes: 260°C Max. for 10 Seconds
- Device Meets MSL 1 Requirements

# **Applications**

- Excellent Alternative to DPAK in Space-Constrained Automotive Applications
- Very Low Leakage for Higher Temperature Operation
- Output Rectification in Compact Portable Consumer Applications

1

• Freewheeling Diode used with Inductive Loads



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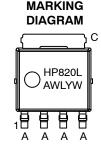
www.onsemi.com

# ULTRAFAST RECTIFIERS 8 AMPERES 200 VOLTS





LFPAK4 CASE 760AB



HP820L = Specific Device Code A = Assembly Location

WL = Wafer Lot
 Y = Year
 W = Work Week

# **ORDERING INFORMATION**

Device	Package	Shipping†
NHP820LFST1G	LFPAK4 (Pb-Free)	3000 / Tape & Reel
NRVHP820LFST1G	LFPAK4 (Pb-Free)	3000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

#### **MAXIMUM RATINGS**

Rating	Symbol	Value	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	200	V
Average Rectified Forward Current (Rated V <sub>R</sub> , T <sub>C</sub> = 168°C)	I <sub>F(AV)</sub>	8.0	Α
Peak Repetitive Forward Current, (Rated V <sub>R</sub> , Square Wave, 20 kHz, T <sub>C</sub> = 158°C)	I <sub>FRM</sub>	16	А
Non-Repetitive Peak Surge Current (Surge Applied at Rated Load Conditions Halfwave, Single Phase, 60 Hz)	I <sub>FSM</sub>	125	А
Storage Temperature Range	T <sub>stg</sub>	-65 to +175	°C
Operating Junction Temperature	TJ	−55 to +175	°C
ESD Rating (Human Body Model)		3B	
ESD Rating (Machine Model)		C5	
Controlled Avalanche Energy (See Test Circuit in Figures 9 & 10)	W <sub>AVAL</sub>	50	mJ

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

## THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction-to-Ambient, Steady State (Assumes 645 mm² 2 oz. copper bond pad, on a FR4 board)	$R_{ hetaJA}$	44	°C/W
Thermal Resistance, Junction-to-Case, Steady State (Assumes 645 mm² 2 oz. copper bond pad, on a FR4 board)	$R_{ heta JC}$	1.07	°C/W

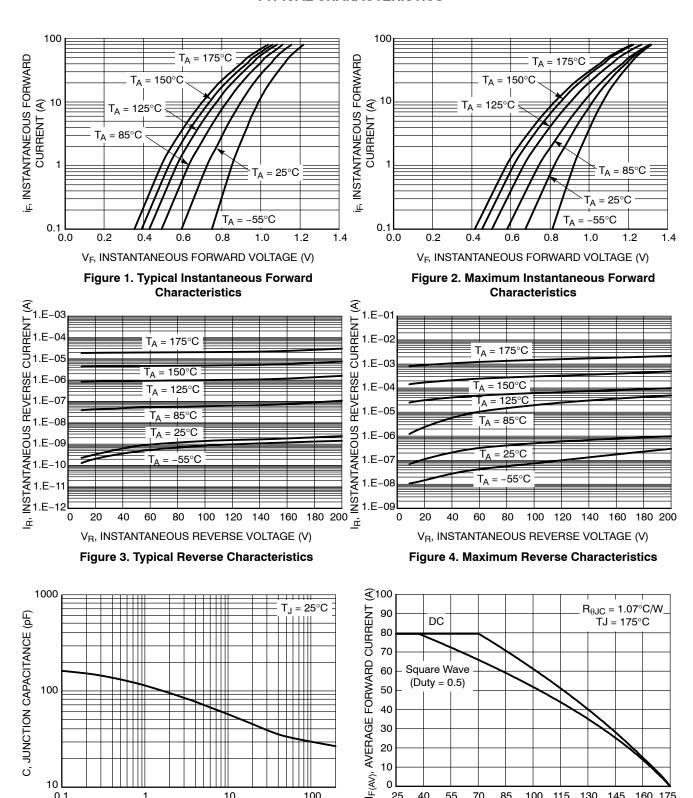
#### **ELECTRICAL CHARACTERISTICS**

Characteristic	Symbol	Max	Unit
Instantaneous Forward Voltage (Note 1)	VF	0.88 1.00	V
Instantaneous Reverse Current (Note 1) (Rated dc Voltage, T <sub>J</sub> = 125°C) (Rated dc Voltage, T <sub>J</sub> = 25°C)	İR	100 1.0	μΑ
Maximum Reverse Recovery Time (I <sub>F</sub> = 1.0 A, di/dt = 50 A/ $\mu$ s, V <sub>R</sub> = 30 V)	T <sub>rr</sub>	35	ns

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

1. Pulse Test: Pulse Width =  $300 \mu s$ , Duty Cycle  $\leq 2.0\%$ .

#### TYPICAL CHARACTERISTICS



V<sub>R</sub>, REVERSE VOLTAGE (V) Figure 5. Typical Junction Capacitance

0.1

10

T<sub>C</sub>, CASE TEMPERATURE (°C) Figure 6. Current Derating per Device

100 115 130

145

85

25 40 55

100

#### **TYPICAL CHARACTERISTICS**

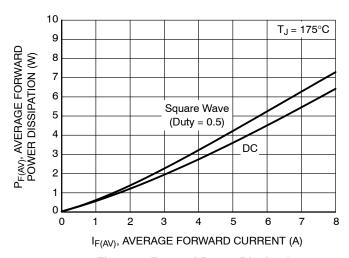


Figure 7. Forward Power Dissipation

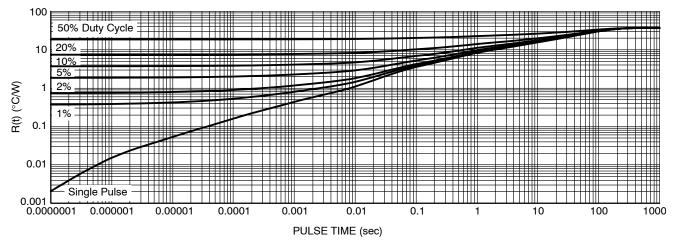


Figure 8. Typical Thermal Characteristics, Junction-to-Ambient

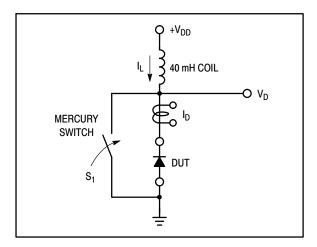


Figure 9. Test Circuit

The unclamped inductive switching circuit shown in Figure 9 was used to demonstrate the controlled avalanche capability of the new "E" series Ultrafast rectifiers. A mercury switch was used instead of an electronic switch to simulate a noisy environment when the switch was being opened.

When  $S_1$  is closed at  $t_0$  the current in the inductor  $I_L$  ramps up linearly; and energy is stored in the coil. At  $t_1$  the switch is opened and the voltage across the diode under test begins to rise rapidly, due to di/dt effects, when this induced voltage reaches the breakdown voltage of the diode, it is clamped at  $BV_{DUT}$  and the diode begins to conduct the full load current which now starts to decay linearly through the diode, and goes to zero at  $t_2$ .

By solving the loop equation at the point in time when  $S_1$  is opened; and calculating the energy that is transferred to the diode it can be shown that the total energy transferred is equal to the energy stored in the inductor plus a finite amount of energy from the  $V_{DD}$  power supply while the diode is in breakdown (from  $t_1$  to  $t_2$ ) minus any losses due to finite

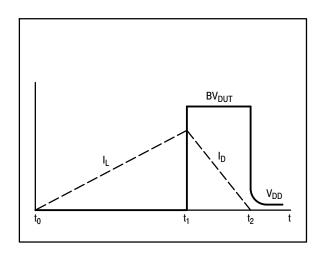


Figure 10. Current-Voltage Waveforms

component resistances. Assuming the component resistive elements are small Equation (1) approximates the total energy transferred to the diode. It can be seen from this equation that if the  $V_{DD}$  voltage is low compared to the breakdown voltage of the device, the amount of energy contributed by the supply during breakdown is small and the total energy can be assumed to be nearly equal to the energy stored in the coil during the time when  $S_1$  was closed, Equation (2).

## **EQUATION (1):**

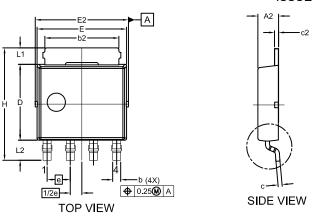
$$W_{AVAL} \approx \frac{1}{2}LI_{LPK}^{2} \left( \frac{BV_{DUT}}{BV_{DUT} - V_{DD}} \right)$$

## **EQUATION (2):**

$$W_{AVAL} \approx \frac{1}{2}LI_{LPK}^2$$

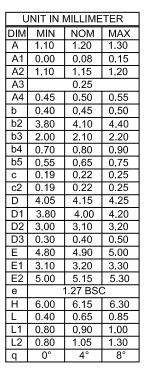
#### PACKAGE DIMENSIONS

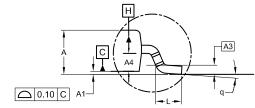
#### LFPAK4 5x6 CASE 760AB **ISSUE B**



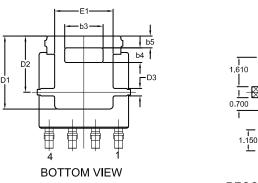
#### NOTES:

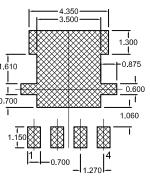
- DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
- CONTROLLING DIMENSION: MILLIMETERS.
- DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH PROTRUSIONS, OR BURRS. MOLD FLASH PROTRUSIONS OR GATE BURRS SHALL NOT EXCEED 0.150mm PER SIDE.
- DIMENSIONS D AND E ARE DETERMINED AT THE OUTERMOST EXTREMES OF THE PLASTIC BODY.
- DATUMS A AND B ARE DETERMINED AT DATUM PLANE H.





DETAIL 'A' SCALE: 2:1





RECOMMENDED MOUNTING **FOOTPRINT** 

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